# MSKSEMI















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# Broduct data sheet





SOD-523

## **1N4448X** FAST SWITCHING DIODE

#### **FEATURES**

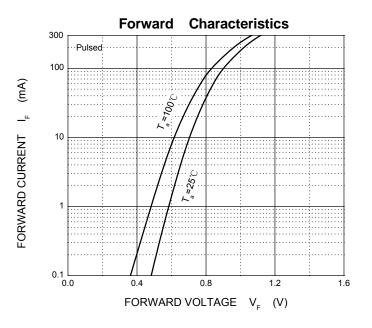
- Small Package
- Low Reverse Current
- Fast Switching Speed
- Surface Mount Package Ideally Suited for Automatic Insertion

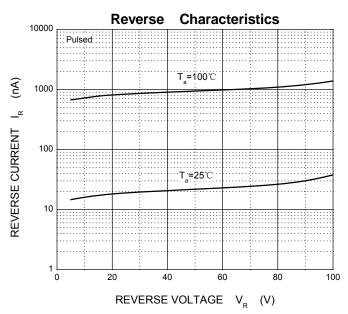
#### Maximum Ratings and Electrical Characteristics, Single Diode @Ta=25℃

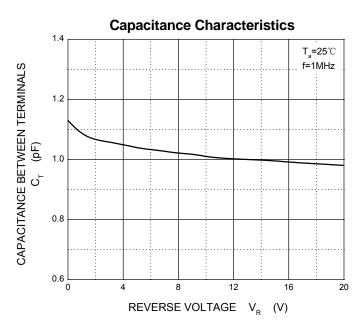
Parameter	Symbol	Limit	Unit
Non-Repetitive Peak Reverse Voltage	$V_{RM}$	100	V
Peak Repetitive Peak Reverse Voltage	$V_{RRM}$	100	
Working Peak Reverse Voltage	$V_{RWM}$	100	V
DC Blocking Voltage	$V_{R}$	75	
RMS Reverse Voltage	$V_{\text{R}(\text{RMS})}$	53	V
Forward Continuous Current	I <sub>FM</sub>	500	mA
Average Rectified Output Current	lo	250	mA
Non-Repetitive Peak Forward Surge Current @t=8.3ms	I <sub>FSM</sub>	2.0	Α
Power Dissipation	Pd	150	mW
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	833	°C/W
Junction Temperature	Tj	150	℃
Storage Temperature	T <sub>STG</sub>	-55~+150	°C

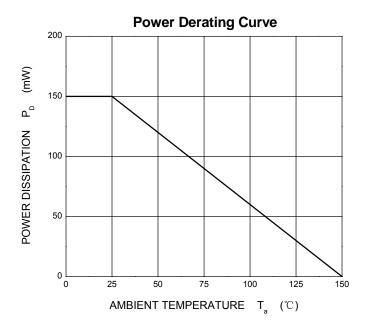
#### Electrical Ratings @Ta=25℃

Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Develope brookslows walkens	V <sub>(BR)R</sub>	75			V	IR=5 A μ
Reverse breakdown voltage	V <sub>(BR)R</sub>	100			V	IR=100μA
Forward voltage	V <sub>F1</sub>	0.62		0.72	V	I <sub>F</sub> =5mA
	V <sub>F2</sub>			1.0	V	I <sub>F</sub> =100mA
Reverse current	I <sub>R</sub>			25	nA	V <sub>R</sub> =20V
Capacitance between terminals	C <sub>T</sub>			4	pF	V <sub>R</sub> =0V,f=1MHz
Reverse recovery time	t <sub>rr</sub>			4	ns	I <sub>F</sub> =I <sub>R</sub> =10mA
ineverse recovery unite	urr -					Irr=0.1 $XI_R$ , $R_L$ =100 $\Omega$



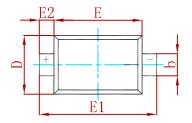


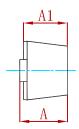


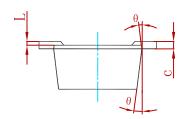




#### **PACKAGE MECHANICAL DATA**

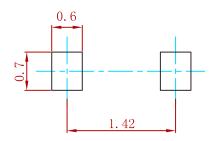






Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	0.510	0.770	0.020	0.031	
A1	0.500	0.700	0.020	0.028	
b	0.250	0.350	0.010	0.014	
С	0.080	0.150	0.003	0.006	
D	0.750	0.850	0.030	0.033	
E	1.100	1.300	0.043	0.051	
E1	1.500	1.700	0.059	0.067	
E2	0.200 REF		0.008 REF		
L	0.010	0.070	0.001	0.003	
θ	7° F	REF	7° F	REF	

### **Suggested Pad Layout**



#### Note:

- 1.Controlling dimension:in millimeters.
- 2.General tolerance:±0.05mm.
  3.The pad layout is for reference purposes only.

#### **REEL SPECIFICATION**

P/N	PKG	QTY
1N4448X	SOD-523	3000



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